

74AVC1T1004

1-to-4 fan-out buffer

Rev. 1 — 23 April 2018

Product data sheet

1 General description

The 74AVC1T1004 is a translating 1-to-4 fan-out buffer suitable for use in clock distribution. It has dual supplies ($V_{CC(A)}$ and $V_{CC(B)}$) for voltage translation. It also has a data input (A), four data outputs (Y_n) and an output enable input (\overline{OE}). $V_{CC(A)}$ and $V_{CC(B)}$ can be independently supplied at any voltage between 0.8 V and 3.6 V. It makes the device suitable for low voltage translation between any of the following voltages: 0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V and 3.3 V. The levels of A and \overline{OE} are referenced to $V_{CC(A)}$, outputs Y_n are referenced to $V_{CC(B)}$. This supply configuration ensures that the fanned out signals can be used in level shifting. A HIGH on \overline{OE} causes all outputs to be pulled LOW via pull-down resistors, a LOW on \overline{OE} disconnects the pull-down resistors and enables all outputs.

Schmitt trigger action at all inputs makes the circuit tolerant for slower input rise and fall time.

The I_{OFF} circuitry disables the output, preventing any damaging backflow current through the device when it is powered down.

2 Features and benefits

- Wide supply voltage range:
 - $V_{CC(A)}$: 0.8 V to 3.6 V
 - $V_{CC(B)}$: 0.8 V to 3.6 V
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM ANSI/ESDA/JEDEC JS-001 Class 2 exceeds 2 kV
 - CDM JESD22-C101 exceeds 1000 V
- Maximum data rates:
 - 380 Mbit/s (\geq 1.8 V to 3.3 V translation)
 - 200 Mbit/s (\geq 1.1 V to 3.3 V translation)
 - 200 Mbit/s (\geq 1.1 V to 2.5 V translation)
 - 200 Mbit/s (\geq 1.1 V to 1.8 V translation)
 - 150 Mbit/s (\geq 1.1 V to 1.5 V translation)
 - 100 Mbit/s (\geq 1.1 V to 1.2 V translation)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3 Ordering information

Table 1. Ordering information

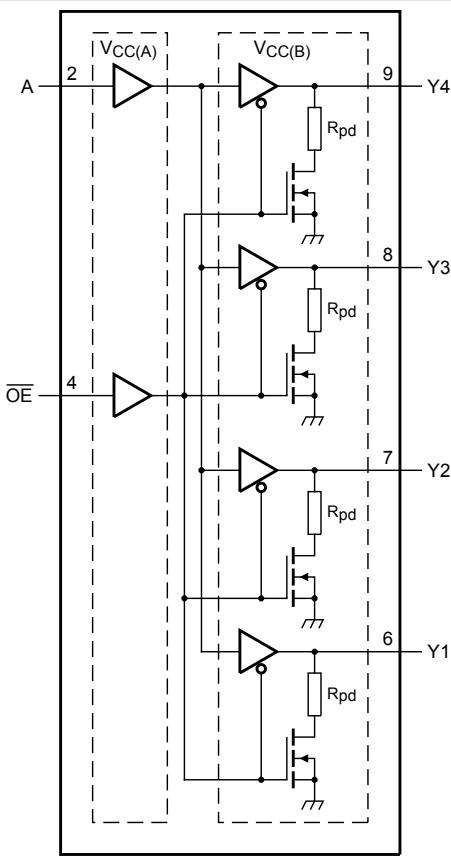
Type number	Package			
	Temperature range	Name	Description	Version
74AVC1T1004DP	-40 °C to +125 °C	TSSOP10	plastic thin shrink small outline package; 10 leads; body width 3 mm	SOT552-1
74AVC1T1004GU33	-40 °C to +125 °C	X2QFN10	plastic extremely thin small outline package; no leads; 10 terminals; body 1.6 x 1.3 x 0.33 mm	SOT1430-1

4 Marking

Table 2. Marking codes

Type number	Marking code
74AVC1T1004DP	Bc
74AVC1T1004GU33	Bc

5 Functional diagram



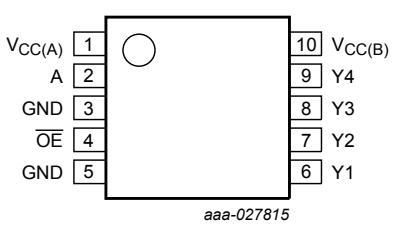
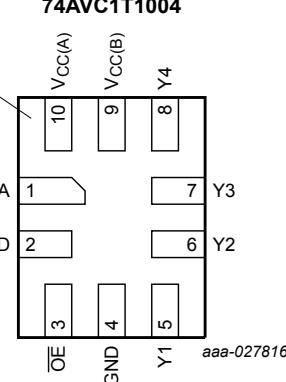
aaa-027814

Pin numbers are shown for TSSOP10 package only.

Figure 1. Logic symbol

6 Pinning information

6.1 Pinning

 <p>74AVC1T1004</p> <p>V_{CC(A)} 1 V_{CC(B)} A 2 Y4 GND 3 Y3 OE 4 Y2 GND 5 Y1</p> <p>aaa-027815</p>	 <p>74AVC1T1004</p> <p>terminal 1 index area</p> <p>V_{CC(A)} 10 V_{CC(B)} 9 Y4 A 1 Y3 GND 2 Y2 OE 3 Y1 GND 4 Y1 5 Y2 6 Y3 7 Y4 8</p> <p>aaa-027816</p> <p>Transparent top view</p>
<p>Figure 2. Pin configuration SOT552-1 (TSSOP10)</p>	<p>Figure 3. Pin configuration SOT1430-1 (X2QFN10)</p>

6.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT552-1	SOT1430-1	
V _{CC(A)}	1	10	supply voltage A
A	2	1	data input (referenced to V _{CC(A)})
GND ^[1]	3, 5	2, 4	ground (0 V)
OE	4	3	output enable input (active LOW) (referenced to V _{CC(A)})
Y1, Y2, Y3, Y4	6, 7, 8, 9	5, 6, 7, 8	data outputs (referenced to V _{CC(B)})
V _{CC(B)}	10	9	supply voltage B

[1] All GND pins must be connected to ground (0 V).

7 Functional description

Table 4. Function table [1]

Inputs		Output
\overline{OE}	A	$\overline{Y_n}$
L	L	L
L	H	H
H	X	L

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

8 Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		-0.5	+4.6	V
$V_{CC(B)}$	supply voltage B		-0.5	+4.6	V
V_I	input voltage	[1]	-0.5	+4.6	V
V_O	output voltage	\overline{OE} = LOW	[1] [2]	-0.5	$V_{CC(B)} + 0.5$
		\overline{OE} = HIGH	[1]	-0.5	+4.6
I_{IK}	input clamping current	$V_I < 0$ V	-50	-	mA
I_{OK}	output clamping current	$V_O < 0$ V	-50	-	mA
I_o	output current	$V_O = 0$ V to $V_{CC(B)}$	-	± 50	mA
I_{CC}	supply current	$I_{CC(A)}$ or $I_{CC(B)}$	-	100	mA
I_{GND}	ground current		-100	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C			
		SOT552-1 package	[3]	-	250 mW
		SOT1430-1 package	[4]	-	250 mW

[1] The minimum input voltage ratings and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] $V_{CC(B)} + 0.5$ V should not exceed 4.6 V.

[3] For SOT552-1 package: above 120 °C, the value of P_{tot} derates linearly with 8.3 mW/K.

[4] For SOT1430-1 package: above 100 °C, the value of P_{tot} derates linearly with 5.2 mW/K.

9 Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		0.8	3.6	V
$V_{CC(B)}$	supply voltage B		0.8	3.6	V
V_I	input voltage		0	3.6	V
V_O	output voltage	\overline{OE} = LOW	0	V_{CCB}	V
		\overline{OE} = HIGH	0	3.6	V
T_{amb}	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC(A)} = 0.8$ V to 3.6 V	0	200	ns/V

10 Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	$T_{amb} = 25$ °C			Unit
			Min	Typ	Max	
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = -1.5$ mA; $V_{CC(B)} = 0.8$ V	-	0.69	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 1.5$ mA; $V_{CC(B)} = 0.8$ V	-	0.07	-	V
I_I	input leakage current	A, \overline{OE} input; $V_I = 0$ V or 3.6 V; $V_{CC(A)} = V_{CC(B)} = 0.8$ V to 3.6 V	-	± 0.025	± 0.25	μA
I_{OFF}	power-off leakage current	V_I or $V_O = 0$ V to 3.6 V; $V_{CC(A)}$ or $V_{CC(B)} = 0$ V	-	± 0.1	± 1	μA
R_{pd}	pull-down resistance		-	50	-	kΩ
C_I	input capacitance	A, \overline{OE} input; $V_I = 0$ V or 3.3 V; $V_{CC(A)} = 3.3$ V	-	1.2	-	pF
C_O	output capacitance	Y_n ; $V_O = 3.3$ V or 0 V; $V_{CC(B)} = 3.3$ V	-	4.7	-	pF

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	$T_{amb} = -40$ °C to +85 °C		$T_{amb} = -40$ °C to +125 °C		Unit
			Min	Max	Min	Max	
V_{IH}	HIGH-level input voltage	A, \overline{OE} input					
		$V_{CC(A)} = 0.8$ V	0.70 $V_{CC(A)}$	-	0.70 $V_{CC(A)}$	-	V
		$V_{CC(A)} = 1.1$ V to 1.95 V	0.65 $V_{CC(A)}$	-	0.65 $V_{CC(A)}$	-	V
		$V_{CC(A)} = 2.3$ V to 2.7 V	1.6	-	1.6	-	V
		$V_{CC(A)} = 3.0$ V to 3.6 V	2	-	2	-	V

Symbol	Parameter	Conditions	$T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$		$T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		Unit
			Min	Max	Min	Max	
V_{IL}	LOW-level input voltage	A, \overline{OE} input					
		$V_{CC(A)} = 0.8\text{ V}$	-	$0.30V_{CC(A)}$	-	$0.30V_{CC(A)}$	V
		$V_{CC(A)} = 1.1\text{ V}$ to 1.95 V	-	$0.35V_{CC(A)}$	-	$0.35V_{CC(A)}$	V
		$V_{CC(A)} = 2.3\text{ V}$ to 2.7 V	-	0.7	-	0.7	V
		$V_{CC(A)} = 3.0\text{ V}$ to 3.6 V	-	0.8	-	0.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}					
		$I_O = -100\text{ }\mu\text{A}$; $V_{CC(B)} = 0.8\text{ V}$ to 3.6 V	$V_{CC(B)} - 0.1$	-	$V_{CC(B)} - 0.1$	-	V
		$I_O = -3\text{ mA}$; $V_{CC(B)} = 1.1\text{ V}$	0.85	-	0.85	-	V
		$I_O = -6\text{ mA}$; $V_{CC(B)} = 1.4\text{ V}$	1.05	-	1.05	-	V
		$I_O = -8\text{ mA}$; $V_{CC(B)} = 1.65\text{ V}$	1.2	-	1.2	-	V
		$I_O = -9\text{ mA}$; $V_{CC(B)} = 2.3\text{ V}$	1.75	-	1.75	-	V
		$I_O = -12\text{ mA}$; $V_{CC(B)} = 3.0\text{ V}$	2.3	-	2.3	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}					
		$I_O = 100\text{ }\mu\text{A}$; $V_{CC(B)} = 0.8\text{ V}$ to 3.6 V	-	0.1	-	0.1	V
		$I_O = 3\text{ mA}$; $V_{CC(B)} = 1.1\text{ V}$	-	0.25	-	0.25	V
		$I_O = 6\text{ mA}$; $V_{CC(B)} = 1.4\text{ V}$	-	0.35	-	0.35	V
		$I_O = 8\text{ mA}$; $V_{CC(B)} = 1.65\text{ V}$	-	0.45	-	0.45	V
		$I_O = 9\text{ mA}$; $V_{CC(B)} = 2.3\text{ V}$	-	0.55	-	0.55	V
		$I_O = 12\text{ mA}$; $V_{CC(B)} = 3.0\text{ V}$	-	0.7	-	0.7	V
I_I	input leakage current	A, \overline{OE} input; $V_I = 0\text{ V}$ or 3.6 V ; $V_{CC(A)} = V_{CC(B)} = 0.8\text{ V}$ to 3.6 V	-	± 1	-	± 5	μA
I_{OFF}	power-off leakage current	V_I or $V_O = 0\text{ V}$ to 3.6 V ; $V_{CC(B)} = 0\text{ V}$; $V_{CC(A)} = 0.8\text{ V}$ to 3.6 V	-	± 5	-	± 30	μA
$I_{CC(A)}$	supply current A	$V_I = 0\text{ V}$ or $V_{CC(A)}$; $I_O = 0\text{ A}$; $V_{CC(A)} = 0.8\text{ V}$ to 3.6 V ; $V_{CC(B)} = 0.8\text{ V}$ to 3.6 V	-	8	-	50	μA
$I_{CC(B)}$	supply current B	$V_I = 0\text{ V}$ or $V_{CC(A)}$; $I_O = 0\text{ A}$; $V_{CC(A)} = 0.8\text{ V}$ to 3.6 V ; $V_{CC(B)} = 0.8\text{ V}$ to 3.6 V	-	8	-	50	μA

11 Dynamic characteristics

Table 9. Typical dynamic characteristics at $V_{CC(A)} = 0.8 \text{ V}$ and $T_{amb} = 25^\circ\text{C}$ ^[1]

Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 6](#); for waveforms, see [Figure 4](#) and [Figure 5](#).

Symbol	Parameter	Conditions	$V_{CC(B)}$						Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
t_{pd}	propagation delay	A to Y_n	29	16	15	15	14	14	ns
t_{dis}	disable time	\overline{OE} to Y_n	25	15	14	14	14	15	ns
t_{en}	enable time	OE to Y_n	33	18	16	16	15	15	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL} ;

t_{dis} is the same as t_{PLZ} and t_{PHZ} ;

t_{en} is the same as t_{PZL} and t_{PZH} .

Table 10. Typical dynamic characteristics at $V_{CC(B)} = 0.8 \text{ V}$ and $T_{amb} = 25^\circ\text{C}$ ^[1]

Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 6](#); for waveforms, see [Figure 4](#) and [Figure 5](#).

Symbol	Parameter	Conditions	$V_{CC(A)}$						Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
t_{pd}	propagation delay	A to Y_n	29	20	20	19	19	18	ns
t_{dis}	disable time	\overline{OE} to Y_n	25	17	16	16	15	15	ns
t_{en}	enable time	OE to Y_n	33	24	23	23	22	22	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL} ;

t_{dis} is the same as t_{PLZ} and t_{PHZ} ;

t_{en} is the same as t_{PZL} and t_{PZH} .

Table 11. Dynamic characteristics for temperature range -40 °C to +85 °C [1]Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 6](#); for waveforms, see [Figure 4](#) and [Figure 5](#).

Symbol	Parameter	Conditions	V _{CC(B)}										Unit
			1.2 V±0.1 V		1.5 V±0.1 V		1.8 V±0.15 V		2.5 V±0.2 V		3.3 V±0.3 V		
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V_{CC(A)} = 1.1 V to 1.3 V													
t _{pd}	propagation delay	A to Y _n	0.9	14.7	0.8	11.2	0.7	9.9	0.6	8.8	0.6	8.5	ns
t _{dis}	disable time	OE to Y _n	1.0	14.7	0.9	12.2	0.9	12.1	0.8	10.8	1.0	11.7	ns
t _{en}	enable time	OE to Y _n	1.0	15.8	0.8	11.8	0.8	10.3	0.7	8.9	0.7	8.5	ns
V_{CC(A)} = 1.4 V to 1.6 V													
t _{pd}	propagation delay	A to Y _n	0.8	13.2	0.7	9.5	0.6	8.2	0.5	6.7	0.5	6.2	ns
t _{dis}	disable time	OE to Y _n	0.9	12.4	0.8	9.7	0.8	9.7	0.7	8.3	0.9	9.0	ns
t _{en}	enable time	OE to Y _n	0.9	14.0	0.7	9.9	0.7	8.5	0.6	6.9	0.6	6.2	ns
V_{CC(A)} = 1.65 V to 1.95 V													
t _{pd}	propagation delay	A to Y _n	0.8	12.5	0.7	8.9	0.6	7.6	0.5	6.1	0.5	5.4	ns
t _{dis}	disable time	OE to Y _n	0.9	11.7	0.8	9.0	0.8	8.8	0.7	7.4	0.8	8.2	ns
t _{en}	enable time	OE to Y _n	0.9	13.5	0.7	9.3	0.6	7.9	0.6	6.3	0.5	5.6	ns
V_{CC(A)} = 2.3 V to 2.7 V													
t _{pd}	propagation delay	A to Y _n	0.8	12.0	0.6	8.3	0.6	6.9	0.5	5.4	0.4	4.7	ns
t _{dis}	disable time	OE to Y _n	0.9	11.0	0.7	8.3	0.8	8.0	0.6	6.5	0.8	7.2	ns
t _{en}	enable time	OE to Y _n	0.8	12.8	0.7	8.7	0.6	7.3	0.5	5.5	0.5	4.8	ns
V_{CC(A)} = 3.0 V to 3.6 V													
t _{pd}	propagation delay	A to Y _n	0.8	11.6	0.6	8.0	0.5	6.5	0.5	5.1	0.4	4.4	ns
t _{dis}	disable time	OE to Y _n	0.9	10.8	0.7	8.0	0.7	7.7	0.6	6.2	0.7	6.9	ns
t _{en}	enable time	OE to Y _n	0.8	12.5	0.6	8.4	0.6	6.9	0.5	5.2	0.5	4.5	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL};t_{dis} is the same as t_{PLZ} and t_{PHZ};t_{en} is the same as t_{PZL} and t_{PZH}.

Table 12. Dynamic characteristics for temperature range -40 °C to +125 °C [1]Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 6](#); for waveforms, see [Figure 4](#) and [Figure 5](#).

Symbol	Parameter	Conditions	V _{CC(B)}										Unit
			1.2 V±0.1 V		1.5 V±0.1 V		1.8 V±0.15 V		2.5 V±0.2 V		3.3 V±0.3 V		
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V_{CC(A)} = 1.1 V to 1.3 V													
t _{pd}	propagation delay	A to Y _n	0.9	15.7	0.8	12.1	0.7	10.8	0.6	9.7	0.6	9.3	ns
t _{dis}	disable time	OE to Y _n	1.0	16.5	0.9	13.8	0.9	13.7	0.8	12.3	1.0	13.1	ns
t _{en}	enable time	OE to Y _n	1.0	16.9	0.8	12.9	0.8	11.4	0.7	9.7	0.7	9.2	ns
V_{CC(A)} = 1.4 V to 1.6 V													
t _{pd}	propagation delay	A to Y _n	0.8	14.1	0.7	10.4	0.6	9.0	0.5	7.3	0.5	6.8	ns
t _{dis}	disable time	OE to Y _n	0.9	14.0	0.8	11.0	0.8	11.0	0.7	9.5	0.9	10.2	ns
t _{en}	enable time	OE to Y _n	0.9	15.1	0.7	10.9	0.7	9.3	0.6	7.6	0.6	6.8	ns
V_{CC(A)} = 1.65 V to 1.95 V													
t _{pd}	propagation delay	A to Y _n	0.8	13.6	0.7	9.7	0.6	8.3	0.5	6.7	0.5	6.0	ns
t _{dis}	disable time	OE to Y _n	0.9	13.4	0.8	10.2	0.8	10.0	0.7	8.4	0.8	9.2	ns
t _{en}	enable time	OE to Y _n	0.9	14.5	0.7	10.2	0.6	8.7	0.6	6.9	0.5	6.2	ns
V_{CC(A)} = 2.3 V to 2.7 V													
t _{pd}	propagation delay	A to Y _n	0.8	12.9	0.6	9.1	0.6	7.6	0.5	5.9	0.4	5.2	ns
t _{dis}	disable time	OE to Y _n	0.9	12.5	0.7	9.4	0.8	9.1	0.6	7.5	0.8	8.2	ns
t _{en}	enable time	OE to Y _n	0.8	13.7	0.7	9.5	0.6	8.0	0.5	6.1	0.5	5.3	ns
V_{CC(A)} = 3.0 V to 3.6 V													
t _{pd}	propagation delay	A to Y _n	0.8	12.5	0.6	8.7	0.5	7.2	0.5	5.6	0.4	4.9	ns
t _{dis}	disable time	OE to Y _n	0.9	12.1	0.7	9.1	0.7	8.8	0.6	7.1	0.7	7.7	ns
t _{en}	enable time	OE to Y _n	0.8	13.4	0.6	9.2	0.6	7.6	0.5	5.7	0.5	4.9	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL};t_{dis} is the same as t_{PLZ} and t_{PHZ};t_{en} is the same as t_{PZL} and t_{PZH}.

Table 13. Dynamic characteristics for temperature range -40 °C to +85 °C and -40 °C to +125 °CVoltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 6](#).

Symbol	Parameter	Conditions	$V_{CC(A)} = V_{CC(B)}$					Unit
			1.2 V \pm 0.1 V	1.5 V \pm 0.1 V	1.8 V \pm 0.15 V	2.5 V \pm 0.2 V	3.3 V \pm 0.3 V	
			Max	Max	Max	Max	Max	
$T_{amb} = -40 \text{ }^{\circ}\text{C to } +85 \text{ }^{\circ}\text{C}$								
$t_{sk(o)}$	output skew time	between any output	0.7	0.4	0.3	0.2	0.2	ns
$T_{amb} = -40 \text{ }^{\circ}\text{C to } +125 \text{ }^{\circ}\text{C}$								
$t_{sk(o)}$	output skew time	between any output	0.9	0.5	0.4	0.3	0.2	ns

Table 14. Typical power dissipation capacitance at $T_{amb} = 25 \text{ }^{\circ}\text{C}$ [1] [2]

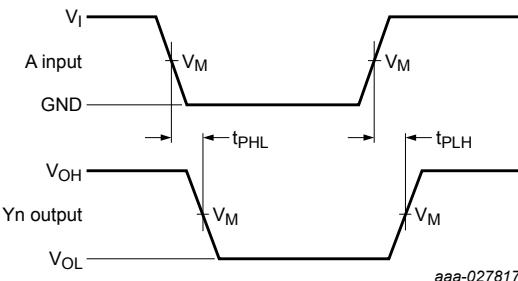
Symbol	Parameter	Conditions	$V_{CC(A)} = V_{CC(B)}$						Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
C_{PD}	power dissipation capacitance	Yn; outputs enabled	36	36	37	37	41	46	pF
		Yn; outputs disabled	2.9	3.2	3.4	3.5	3.7	3.9	pF

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

 f_i = input frequency in MHz; f_o = output frequency in MHz; C_L = load capacitance in pF; V_{CC} = supply voltage in V; $\sum(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.[2] $f_i = 10 \text{ MHz}$; $V_i = \text{GND to } V_{CC(A)}$; $t_r = t_f = 1 \text{ ns}$; $C_L = 0 \text{ pF}$; $R_L = \infty \text{ } \Omega$.

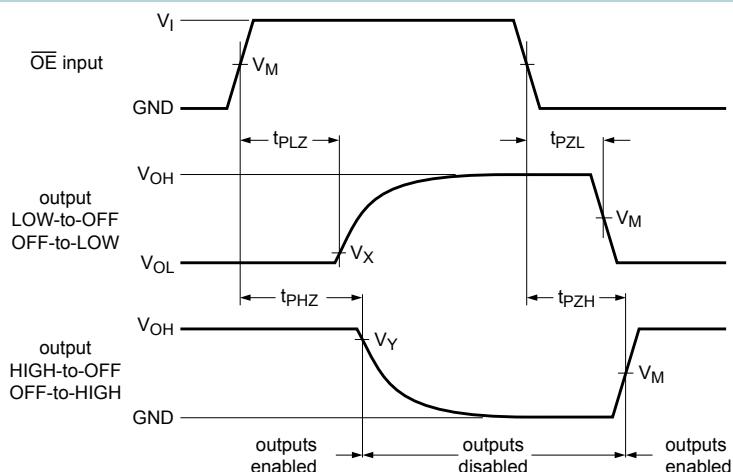
11.1 Waveforms and test circuit



Measurement points are given in [Table 15](#).

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 4. The data input (A) to output (Yn) propagation delay times



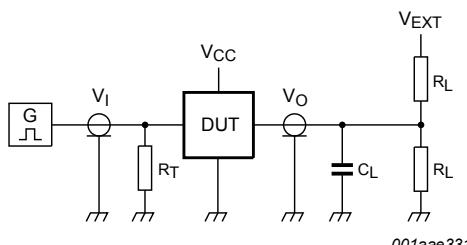
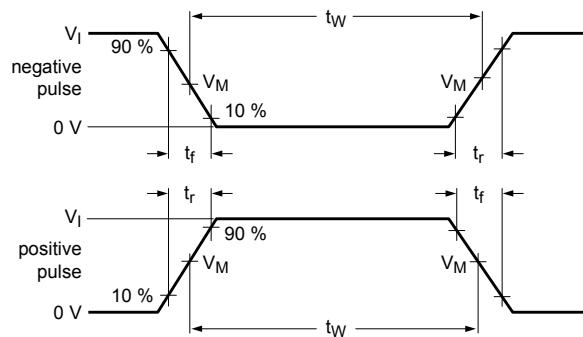
Measurement points are given in [Table 15](#).

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 5. Enable and disable times

Table 15. Measurement points

Supply voltage	Input	Output		
$V_{CC(A)}, V_{CC(B)}$	V_M	V_M	V_X	V_Y
0.8 V to 1.6 V	$0.5V_{CC(A)}$	$0.5V_{CC(B)}$	$V_{OL} + 0.1$ V	$V_{OH} - 0.1$ V
1.65 V to 2.7 V	$0.5V_{CC(A)}$	$0.5V_{CC(B)}$	$V_{OL} + 0.15$ V	$V_{OH} - 0.15$ V
3.0 V to 3.6 V	$0.5V_{CC(A)}$	$0.5V_{CC(B)}$	$V_{OL} + 0.3$ V	$V_{OH} - 0.3$ V



001aae331

Test data is given in [Table 16](#)

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance.

V_{EXT} = External voltage for measuring switching times.

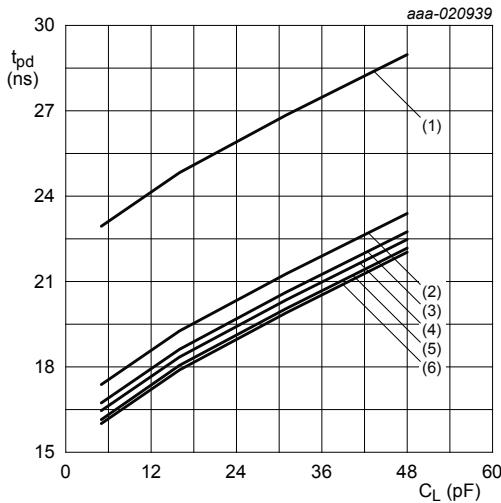
Figure 6. Test circuit for measuring switching times

Table 16. Test data

Supply voltage	Input		Load		V_{EXT}		
$V_{CC(A)}, V_{CC(B)}$	V_I	$\Delta t/\Delta V^{[1]}$	C_L	R_L	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
0.8 V to 1.6 V	$V_{CC(A)}$	$\leq 1.0 \text{ ns/V}$	15 pF	2 k Ω	open	GND	$2V_{CC(B)}$
1.65 V to 2.7 V	$V_{CC(A)}$	$\leq 1.0 \text{ ns/V}$	15 pF	2 k Ω	open	GND	$2V_{CC(B)}$
3.0 V to 3.6 V	$V_{CC(A)}$	$\leq 1.0 \text{ ns/V}$	15 pF	2 k Ω	open	GND	$2V_{CC(B)}$

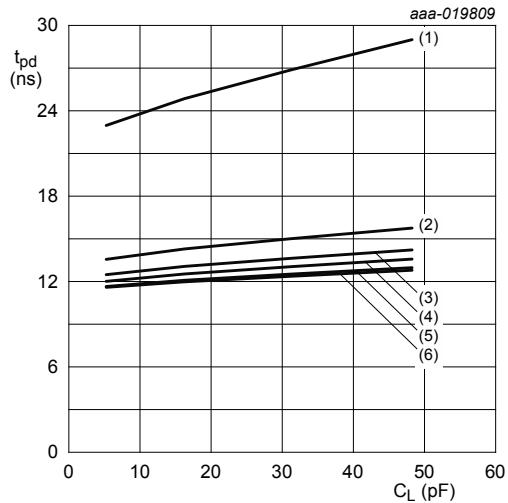
[1] $dV/dt \geq 1.0 \text{ V/ns}$

11.2 Typical propagation delay characteristics



a. Propagation delay (A to Y_n); $V_{CC(B)} = 0.8$ V

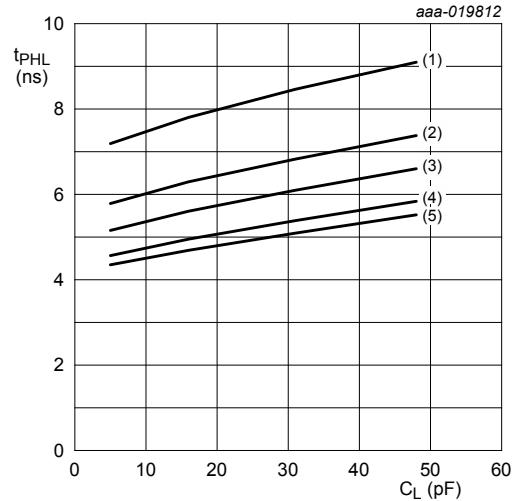
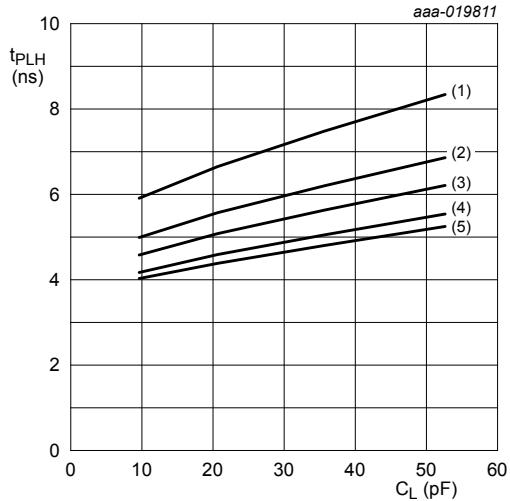
- (1) $V_{CC(A)} = 0.8$ V
- (2) $V_{CC(A)} = 1.2$ V
- (3) $V_{CC(A)} = 1.5$ V
- (4) $V_{CC(A)} = 1.8$ V
- (5) $V_{CC(A)} = 2.5$ V
- (6) $V_{CC(A)} = 3.3$ V



b. Propagation delay (A to Y_n); $V_{CC(A)} = 0.8$ V

- (1) $V_{CC(B)} = 0.8$ V
- (2) $V_{CC(B)} = 1.2$ V
- (3) $V_{CC(B)} = 1.5$ V
- (4) $V_{CC(B)} = 1.8$ V
- (5) $V_{CC(B)} = 2.5$ V
- (6) $V_{CC(B)} = 3.3$ V

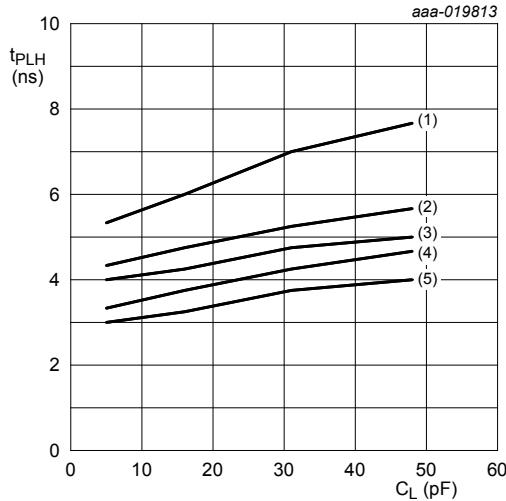
Figure 7. Typical propagation delay versus load capacitance; $T_{amb} = 25$ °C



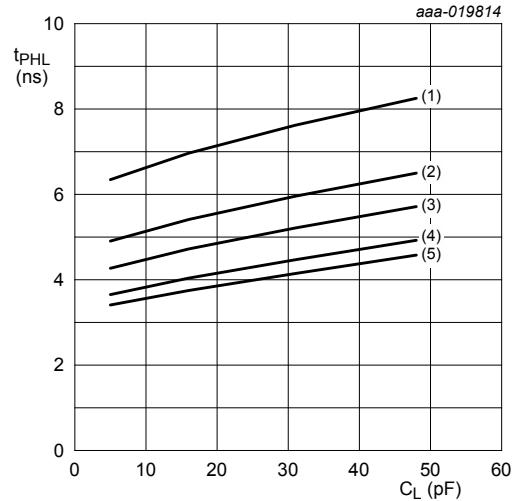
a. LOW to HIGH propagation delay (A to Y_n); $V_{CC(A)} = 1.2$ V b. HIGH to LOW propagation delay (A to Y_n); $V_{CC(A)} = 1.2$ V

- (1) $V_{CC(B)} = 1.2$ V
- (2) $V_{CC(B)} = 1.5$ V
- (3) $V_{CC(B)} = 1.8$ V
- (4) $V_{CC(B)} = 2.5$ V
- (5) $V_{CC(B)} = 3.3$ V

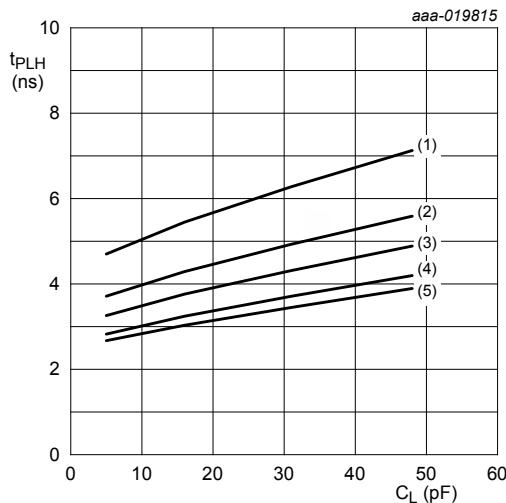
Figure 8. Typical propagation delay versus load capacitance; $T_{amb} = 25$ °C



a. LOW to HIGH propagation delay (A to Yn);
 $V_{CC(A)} = 1.5$ V

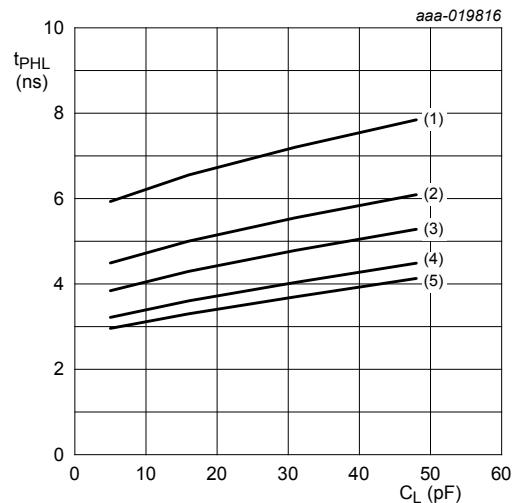


b. HIGH to LOW propagation delay (A to Yn);
 $V_{CC(A)} = 1.5$ V



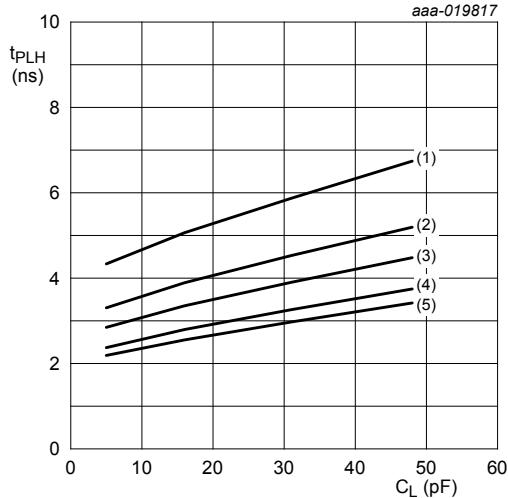
c. LOW to HIGH propagation delay (A to Yn);
 $V_{CC(A)} = 1.8$ V

- (1) $V_{CC(B)} = 1.2$ V
- (2) $V_{CC(B)} = 1.5$ V
- (3) $V_{CC(B)} = 1.8$ V
- (4) $V_{CC(B)} = 2.5$ V
- (5) $V_{CC(B)} = 3.3$ V

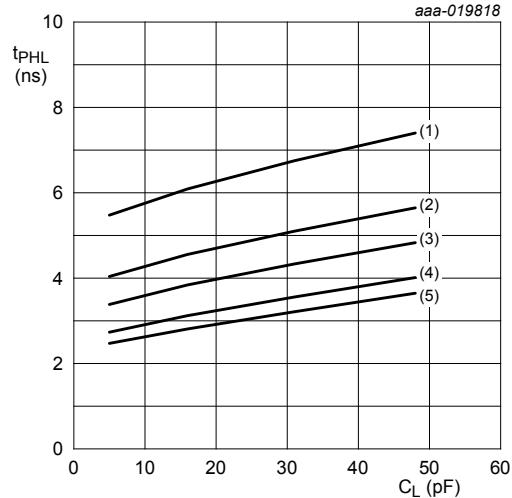


d. HIGH to LOW propagation delay (A to Yn);
 $V_{CC(A)} = 1.8$ V

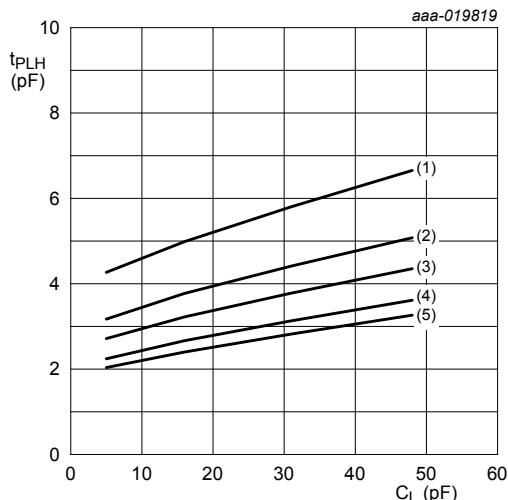
Figure 9. Typical propagation delay versus load capacitance; $T_{amb} = 25$ °C



a. LOW to HIGH propagation delay (A to Y_n);
 $V_{CC(A)} = 2.5$ V

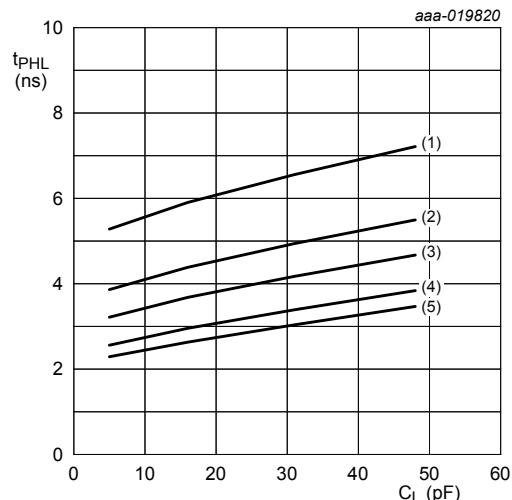


b. HIGH to LOW propagation delay (A to Y_n);
 $V_{CC(A)} = 2.5$ V



c. LOW to HIGH propagation delay (A to Y_n);
 $V_{CC(A)} = 3.3$ V

- (1) $V_{CC(B)} = 1.2$ V
- (2) $V_{CC(B)} = 1.5$ V
- (3) $V_{CC(B)} = 1.8$ V
- (4) $V_{CC(B)} = 2.5$ V
- (5) $V_{CC(B)} = 3.3$ V



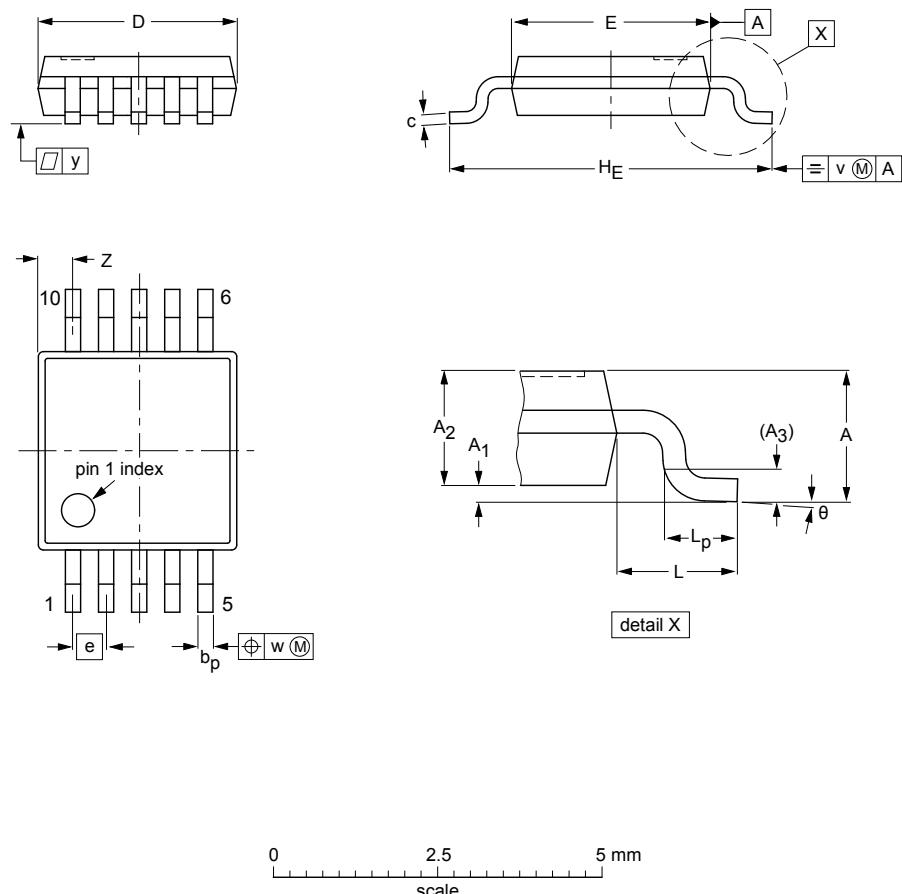
d. HIGH to LOW propagation delay (A to Y_n);
 $V_{CC(A)} = 3.3$ V

Figure 10. Typical propagation delay versus load capacitance; $T_{amb} = 25$ °C

12 Package outline

TSSOP10: plastic thin shrink small outline package; 10 leads; body width 3 mm

SOT552-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	v	w	y	Z ⁽¹⁾	θ
mm	1.1 0.05	0.15 0.80	0.95 0.25	0.25 0.15	0.30 0.15	0.23 0.15	3.1 2.9	3.1 2.9	0.5	5.0 4.8	0.95	0.7 0.4	0.1	0.1	0.1	0.67 0.34	6° 0°

Notes

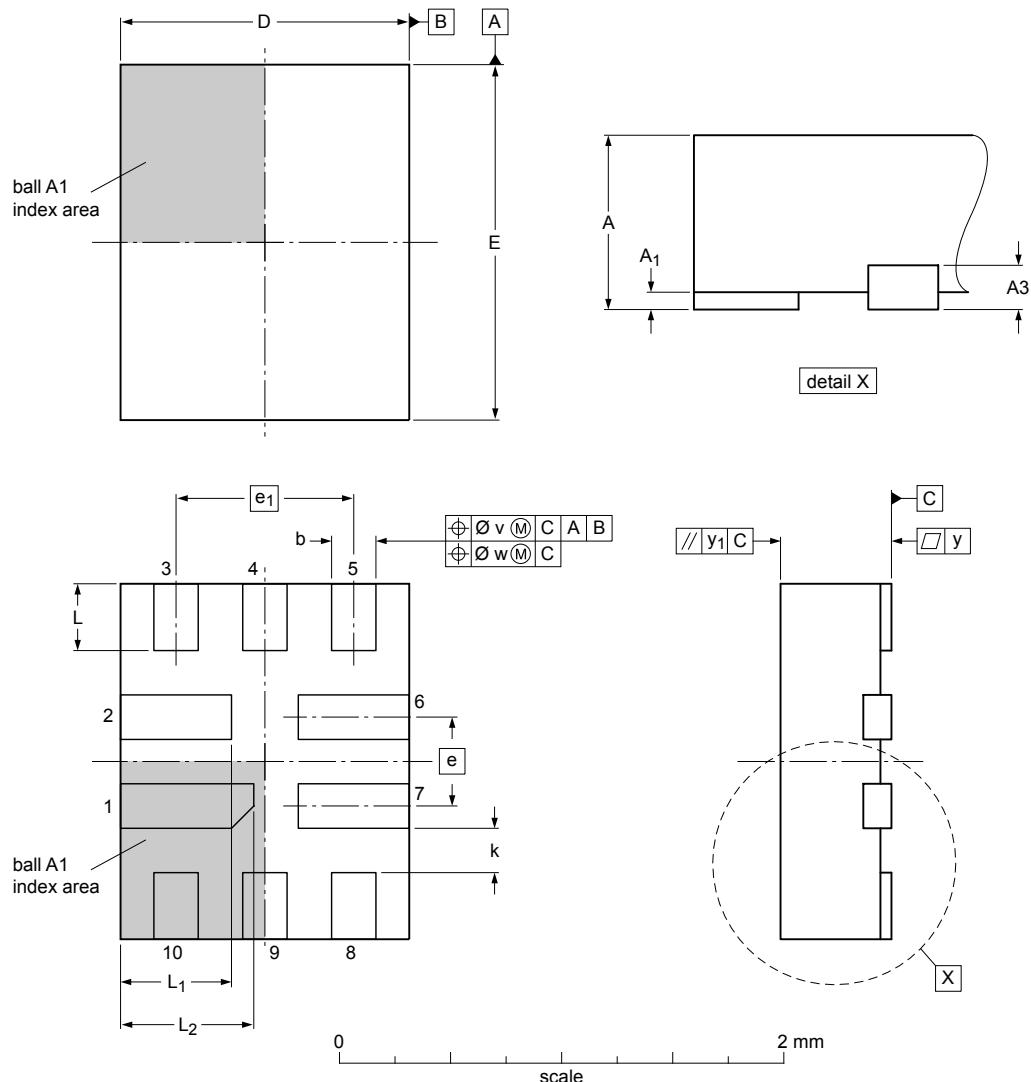
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT552-1						-99-07-29 03-02-18

Figure 11. Package outline SOT552-1 (TSSOP10)

X2QFN10: plastic extremely thin small outline package; no leads; 10 terminals; body 1.6 x 1.3 x 0.33 mm

SOT1430-1



sot1430-1_po

Figure 12. Package outline SOT1430-1 (X2QFN10)

13 Abbreviations

Table 17. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model

14 Revision history

Table 18. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AVC1T1004 v.1	20180423	Product data sheet	-	-

15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.